R07

Set No. 2

II B.Tech I Semester Examinations, May 2011 ELECTRONIC CIRCUIT ANALYSIS

Common to Electronics And Telematics, Electronics And Communication Engineering

Time: 3 hours Max Marks: 80

Answer any FIVE Questions All Questions carry equal marks

- 1. (a) Explain how Switching Regulator overcomes the disadvantage of Series and Shunt type of regulators?
 - (b) Explain why pulse width modulator is used in Switching regulators and also explain the operation of it. [8+8]
- 2. Draw the circuit diagram of a Class-C tuned amplifier. Explain its operation with neat waveforms. Derive the expression for percentage efficiency. [16]
- 3. (a) What is the role of f_T in defining the frequency range for the validity of Hybrid π model of a transistor?
 - (b) Show that $r_{b'e}$ in Hybrid π model, is directly proportional to temperature and inversely proportional to collector current. [8+8]
- 4. (a) For a power supply of 4% voltage regulation and an open circuit output voltage of 48V dc. Calculate the full load voltage of the supply?
 - (b) Explain how Shunt type of regulator gives more current limiting compared to Series type of regulator.
 - (c) The base to emitter voltage of the transistor shown in figure 7c. is 0.7V. V_i can vary from 12V to 24V.
 - i. What breakdown voltage should the zener diode have if the load voltage is to be maintained at 9V?
 - ii. If the zener diode must conduct 10mA of reverse current to remain in breakdown, What maximum value should Rs have?
 - iii. With the value of Rs found in (ii), what is the maximum power dissipated in the zener diode? [4+6+6]

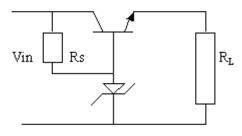


Figure 7c

5. (a) Obtain the theoretical expressions for f_{1n} and f_{2n} when n-stages of identical amplifiers are cascaded.

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- (b) A CE R-C coupled amplifier uses transistors having $h_{oe} = 24\mu A/V$, and $h_{ie} = 1K$. The potential divider biasing resistors are $R_1 = 50K$ and $R_2 = 4K$. The load resistor is $R_C = 1K$. What should be the minimum value of coupling capacitor C_b in order to have lower 3-dB frequency for voltage gain not exceeding 12 Hz. [8+8]
- 6. (a) Draw the circuit diagram of Common Collector amplifier. Derive the expressions for A_I , A_V , R_i , and R_o in terms of h-parameters of CE transistor.
 - (b) For a CE configuration, what is the maximum value of R_S for which R_o differs by no more than 10 percent of its value for $R_S = 0$. The h-parameter values are $h_{fe} = 50$, $h_{ie} = 1.1K\Omega$, $h_{re} = 2.5 \times 10^{-4}$, $h_{oe} = 25\mu A/V$. [10+6]
- 7. (a) State the functions and frequency ranges of operation of tuned amplifiers with relevant reasons?
 - (b) Draw the circuit of a typical single tuned RF amplifier stage employing a transistor. If the tuned circuit contains L=200 μ H,C=126pF, $R_L=15k\Omega$. Calculate the bandwidth of the amplifier? [6+10]
- 8. (a) Define the conversion efficiency of a power amplifier. A class? A power amplifier with a direct coupled load has a collector efficiency of 15% and delivers a power output of 5 Watts. Find
 - i. The DC power input
 - ii. Power dissipation at maximum output

(b) Draw the push-pull power amplifier circuit. Derive the expression for the output current in push-pull amplifier with base current as $i_b = I_{bn} \sin wt$.

[10]

[6]

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Set No. 4

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Common to Electronics And Telematics, Electronics And Communication Engineering

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- 1. Draw the circuit diagram of a Class-C tuned amplifier. Explain its operation with neat waveforms. Derive the expression for percentage efficiency. [16]
- 2. (a) Define the conversion efficiency of a power amplifier. A class ? A power amplifier with a direct coupled load has a collector efficiency of 15% and delivers a power output of 5 Watts. Find
 - i. The DC power input
 - ii. Power dissipation at maximum output

[6]

(b) Draw the push-pull power amplifier circuit. Derive the expression for the output current in push-pull amplifier with base current as $i_b = I_{bn} \sin wt$.

[10]

- 3. (a) Explain how Switching Regulator overcomes the disadvantage of Series and Shunt type of regulators?
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- 5. (a) Obtain the theoretical expressions for f_{1n} and f_{2n} when n-stages of identical amplifiers are cascaded.
 - (b) A CE R-C coupled amplifier uses transistors having $h_{oe} = 24\mu A/V$, and $h_{ie} = 1K$. The potential divider biasing resistors are $R_1 = 50K$ and $R_2 = 4K$. The load resistor is $R_C = 1K$. What should be the minimum value of coupling capacitor C_b in order to have lower 3-dB frequency for voltage gain not exceeding 12 Hz. [8+8]
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7. (a) What is the role of f_T in defining the frequency range for the validity of Hybrid - π model of a transistor?

- (b) Show that $r_{b'e}$ in Hybrid π model, is directly proportional to temperature and inversely proportional to collector current. [8+8]
- 8. (a) For a power supply of 4% voltage regulation and an open circuit output voltage of 48V dc. Calculate the full load voltage of the supply?
 - (b) Explain how Shunt type of regulator gives more current limiting compared to Series type of regulator.
 - (c) The base to emitter voltage of the transistor shown in figure 7c. is 0.7V. V_i can vary from 12V to 24V.
 - i. What breakdown voltage should the zener diode have if the load voltage is to be maintained at 9V?
 - ii. If the zener diode must conduct 10mA of reverse current to remain in breakdown, What maximum value should Rs have?
 - iii. With the value of Rs found in (ii), what is the maximum power dissipated in the zener diode? [4+6+6]

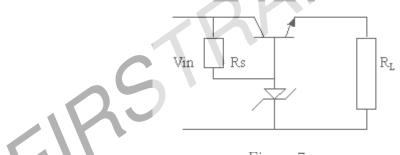


Figure 7c

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Set No. 1

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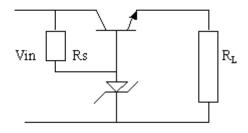


Figure 7c

- 3. (a) Define the conversion efficiency of a power amplifier. A class? A power amplifier with a direct coupled load has a collector efficiency of 15% and delivers a power output of 5 Watts. Find
 - i. The DC power input
 - ii. Power dissipation at maximum output

[6]

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Set No. 1

(b) Draw the push-pull power amplifier circuit. Derive the expression for the output current in push -pull amplifier with base current as $i_b = I_{bn}$ sin wt.

[10]

- 4. (a) Explain how Switching Regulator overcomes the disadvantage of Series and Shunt type of regulators?
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 - (b) For a CE configuration, what is the maximum value of R_S for which R_o differs by no more than 10 percent of its value for $R_S = 0$. The h-parameter values are $h_{fe} = 50$, $h_{ie} = 1.1K\Omega$, $h_{re} = 2.5 \times 10^{-4}$, $h_{oe} = 25\mu A/V$. [10+6]
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(c) The base to emitter voltage of the transistor shown in figure 7c. is 0.7V. V_i can vary from 12V to 24V.

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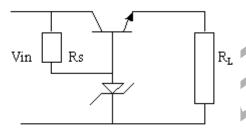


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